

Sr. No.	Description/Specifications	Qty
1	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:20 mm; operating wavelength:1030nm; Input Polarization:Horizontal; Output Polarization:Horizontal; (www.eotech.com, NO ALTERNATE);	1
2	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:15 mm; Wavelength:1030nm Input Polarization:Horizontal; Output Polarization:Horizontal (www.eotech.com, NO ALTERNATE);	1
3	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:25 mm; Wavelength:1030nm Input Polarization:Horizontal; Output Polarization:Horizontal (www.eotech.com, NO ALTERNATE);	2
4	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:20 mm; operating wavelength:1064nm; Input Polarization:Horizontal; Output Polarization:Horizontal (www.eotech.com, NO ALTERNATE);	1
5	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:15 mm; Wavelength:1064nm Input Polarization:Horizontal; Output Polarization:Horizontal (www.eotech.com, NO ALTERNATE);	1
6	PAVOS Optical Isolators - 1010 nm to 1080 nm Clear Aperture:25 mm; Wavelength:1064nm Input Polarization:Horizontal; Output Polarization:Horizontal (www.eotech.com, NO ALTERNATE);	2
7	ET-3010 - InGaAs Photodetector; Rise Time/Fall Time: <175 ps/<175 ps; Bandwidth: >2 GHz; Active Area Diameter: 100 µm; connector: BNC;	2
8	ET-2060- Silicon Photodetector (EOT) Rise Time/Fall Time <320 ps/<320ps; Bandwidth >1.1 GHz;Active Area Diameter 0.4 mm; Output Connector BNC;	2
9	ET-4000- >12.5 GHz GaAs Photodetector (EOT); Rise Time/Fall Time <30 ps/<30 ps;Active Area Diameter: 60 µm; Output Connector:SMA;	1